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Supplementary Information

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Figure S1. A representative cross-sectional SEM view of VOG (S3), indicating a thickness of \sim 30 μ m.



Figure S2. XPS spectrum of O 1s peak that can be fitted with C-O bond at 531.8 eV and C=O bond at 532.9 eV.



Fig. S3. The C-V profiles of samples S1 and S2 at different scan rates from 20 to 200 mV/s for $Fe(CN)_6^{3-/4-}$ redox couple.



Figure S4. Typical Nyquist plots of the impedance responses for a dye-sensitized solar cell using VOG counter electrode measured at two different bias voltages.